NSN 5961-01-109-8522

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-109-8522 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.090 inches **End Application:** Jarleigh burke class ddg, spruance class dd (963), forrestal class cv, kidd class ddg, virginia class cgn (41), los angeles class ssn (688), nimitz class cvn, sturgeon class ssn (637), ticonderoga class cg (47) Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse breakdown voltage, dc **Special Features:** voltage; weapon system essential; junction pattern arrangement: pin **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No